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1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

WWW - For www.nxp.com use www.ween-semi.com

Email - For salesaddresses@nxp.com use salesaddresses@ween-semi.com

For the copyright notice at the bottom of each page (or elsewhere in the document, depending on the version) "© NXP Semiconductors N.V. *{year}*. All rights reserved" becomes "© WeEn Semiconductors Co., Ltd. *{year}*. All rights reserved"

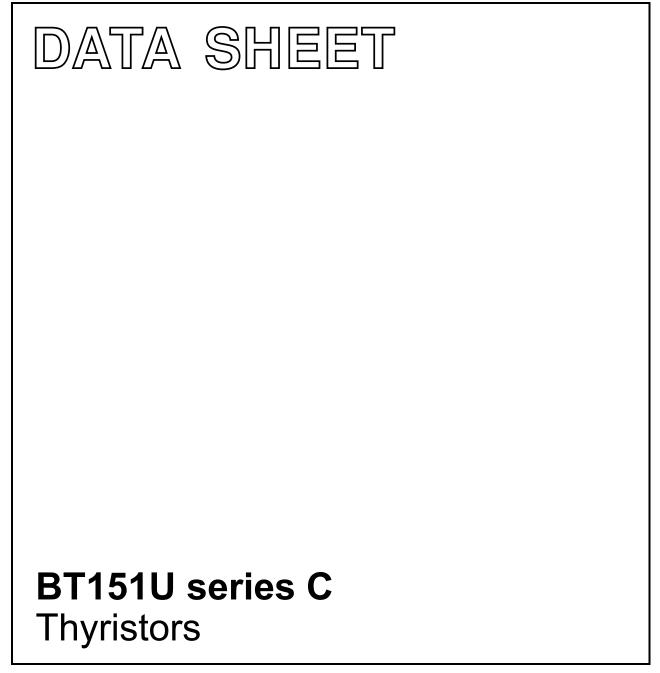
If you have any questions related to this document, please contact our nearest sales office via email or phone (details via <u>salesaddresses@ween-semi.com</u>).

Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS



Product specification

April 2004



BT151U series C

GENERAL DESCRIPTION

Passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

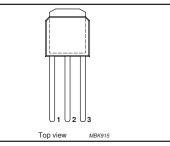
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
$V_{DRM}, \\ V_{RRM} \\ I_{T(AV)} \\ I_{T(RMS)} \\ I_{TSM}$	BT151U- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current	500C 500 7.5 12 100	650C 650 7.5 12 100	800C 800 7.5 12 100	V A A A

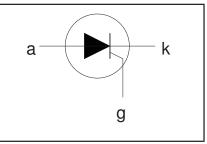
PINNING - SOT533, (I-PAK)

PIN NUMBER	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
$V_{\text{drm}}, V_{\text{rrm}}$	Repetitive peak off-state voltages		-	-500C 500 ¹	-650C 650 ¹	-800C 800	V
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 104$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		7.5 12		A A
		t = 10 ms t = 8.3 ms	-		100 110		A A
l²t dI _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 10 ms I _{TM} = 20 A; I _G = 50 mA; dI _G /dt = 50 mA/μs	-		50 50		A²s A∕µs
I _{GM} V _{RGM} P _{GM}	triggering Peak gate current Peak reverse gate voltage Peak gate power		-		2 5 5		A V W
$\begin{array}{c} I_{GM} \\ P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$	Average gate power Storage temperature Junction temperature	over any 20 ms period	-40 -		0.5 150 125		°℃ ℃

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

BT151U series C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	1.3	K/W K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air	-	70	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

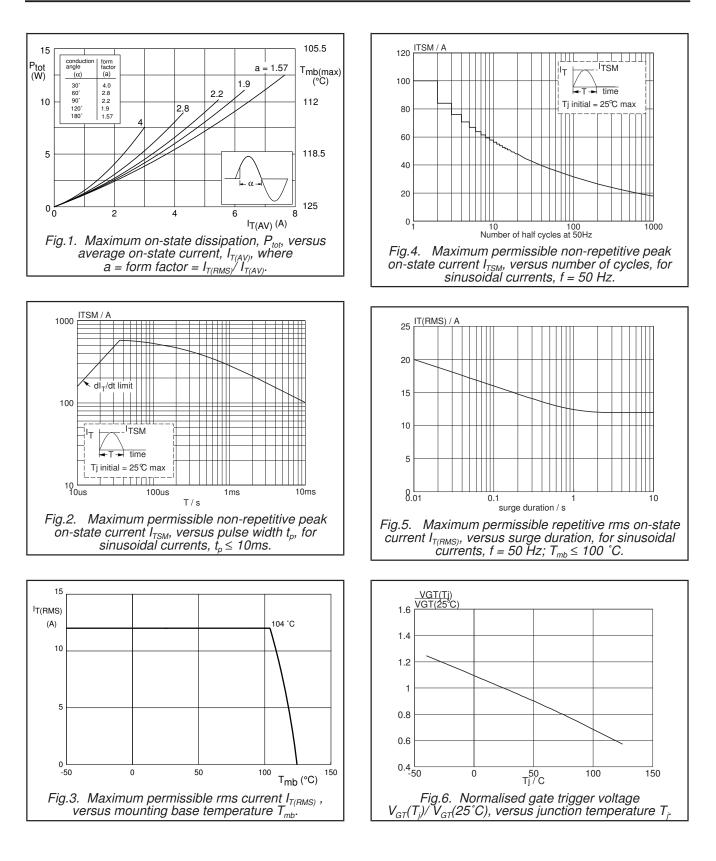
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	2	15	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	10	40	mA
I I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	7	20	mA
İ Ϋ _T	On-state voltage	$I_{T} = 23 \text{ A}$	-	1.44	1.75	V
V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.6	1.5	V
		$V_{D} = V_{DRM(max)}; I_{T} = 0.1 \text{ A}; T_{j} = 125 \text{ °C}$	0.25	0.4	-	V
I _D , I _R	Off-state leakage current	$V_D = V_{DRM(max)}^{Orthm(max)}; V_R = V_{RRM(max)}; T_j = 125 \text{°C}$	-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

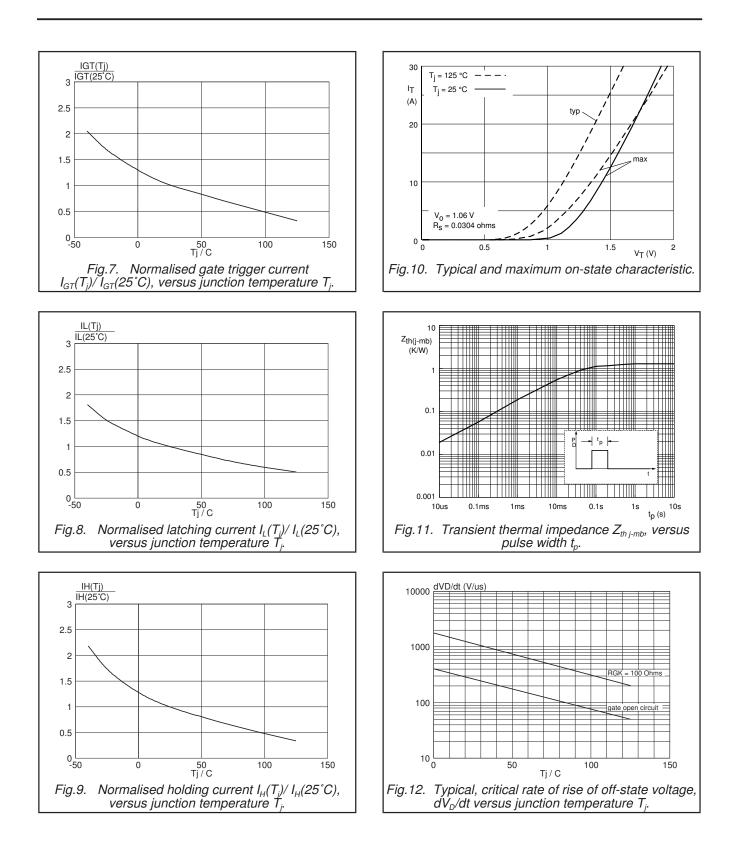
$T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform Gate open circuit	50	130	-	V/µs
t _{gt}	Gate controlled turn-on time	$ \begin{array}{l} R_{GK}^{-} = 100 \ \Omega \\ I_{TM}^{-} = 40 \ A; \ V_{D}^{-} = V_{DRM(max)}; \ I_{G}^{-} = 0.1 \ A; \\ dI_{G}^{-} dI_{G}^{-} dI_{G}^{-} = 5 \ A / \mu s \end{array} $	200	1000 2	-	V/μs μs
t _q	Circuit commutated turn-off time		-	70	-	μs

BT151U series C

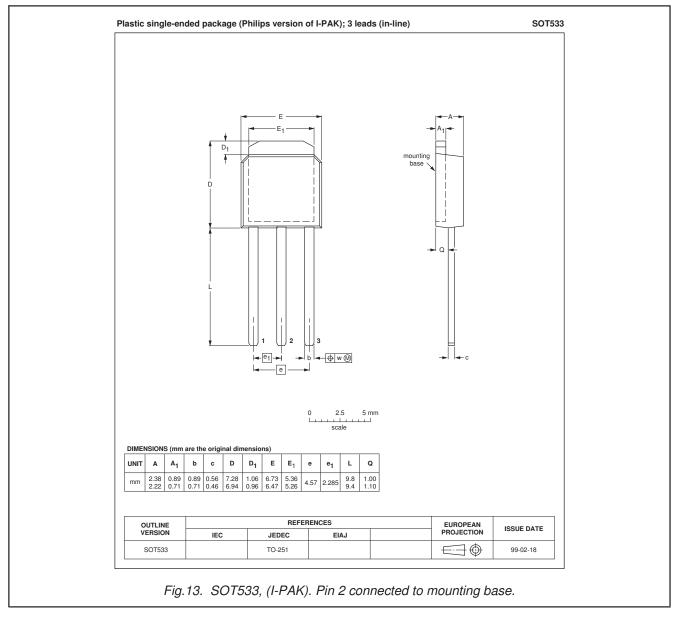


BT151U series C



BT151U series C

MECHANICAL DATA



Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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